Apacer

RoHS Compliant

CFast 2.0

SS220-CFast 2.0 Product Specifications

March 17, 2021

Version 1.6

Specifications Overview:

- **Standard Serial ATA Interface**
    - SATA Revision 3.1 compliance
    - SATA 6 Gb/s interface speed
    - Backward compatible with SATA 1.5 and 3 Gb/s interfaces
    - ATA-compatible command set

- **Capacity**
    - 4, 8, 16, 32, 64 GB

- **Performance***
    - Sequential read: Up to 560 MB/sec
    - Sequential write: Up to 450 MB/sec
    - Random read (4K): Up to 81,000 IOPS
    - Random write (4K): Up to 77,000 IOPS

- **Flash Management**
    - Built-in hardware ECC
    - Global Wear Leveling
    - Flash bad-block management
    - Flash Translation Layer: Page Mapping
    - S.M.A.R.T.
    - Power Failure Management
    - Device Sleep (optional)
    - ATA Secure Erase
    - TRIM

- **NAND Flash Type:** SLC

- **MTBF:** >3,000,000 hours

- **Endurance (in Terabytes Written: TBW)**
    - 4 GB: 186 TBW
    - 8 GB: 267 TBW
    - 16 GB: 535 TBW
    - 32 GB: 1,329 TBW
    - 64 GB: 2,659 TBW

- **Temperature Range**
    - Operating:
        Standard: 0°C to 70°C
        Wide: -40°C to 85°C
    - Storage: -40°C to 100°C

- **Supply Voltage**
    - 3.3 V $\pm$ 5%

- **Power Consumption***
    - Active mode: 510 mA
    - Idle mode: 90 mA

- **Connector Type**
    - 7 + 17 pin female connector

- **Write Protect**

- **RoHS Compliant**

*Varies from capacities. The values for performances and power consumptions presented are typical and may vary depending on flash configurations or platform settings.

Table of Contents

1. General Descriptions

Apacer SS220-CFast 2.0 is the latest enhancement of conventional CFast form factor that delivers various technological advantages. This new flash memory card comes with SATA 6 Gb/s interface for higher performance and consists of SATA-based 7-pin signal segment and 17-pin for power and control purposes. For data efficiency, the internal controlling unit of the SS220-CFast 2.0 is engineered with DRAM for enhanced random performance which achieves data transfer rates up to 560 MB/s in sequential access and 81,000 IOPS in 4KB random access. In addiation, Apacer CFast cards come with S.M.A.R.T. for lifetime monitoring and customization support if write protection is required. Apacer SS220-CFast 2.0 guarantees reliability of applications in harsh environments by implementing intelligent Flash Management algorithms and Error Correction.

2. Functional Block

Apacer SS220-CFast 2.0 includes a single-chip SATA 6 Gb/s and the flash media. The controller integrates the flash management unit to support multi-channel, multi-bank flash arrays. Figure 2-1 shows the functional block diagram.
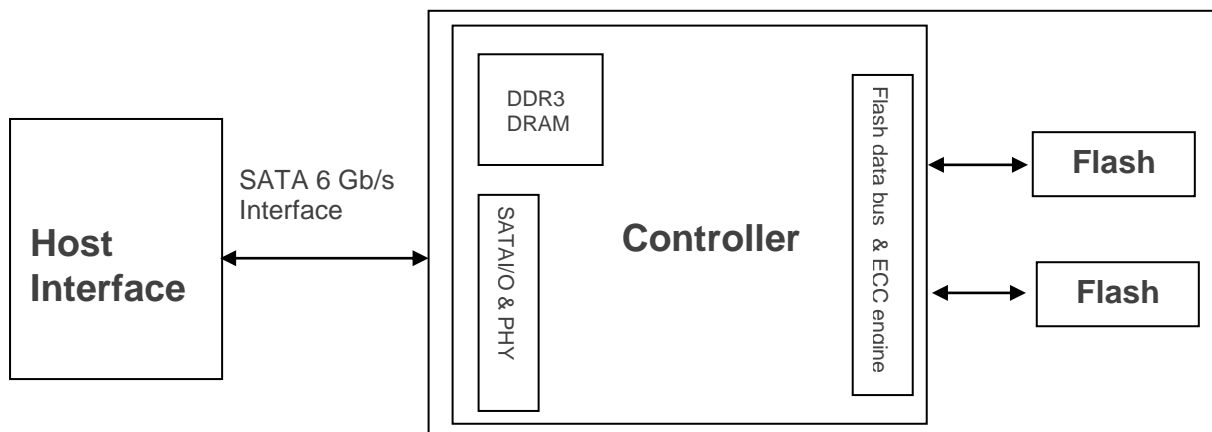
Figure 2-1 Functional Block Diagram

3. Pin Assignments

Table 3-1 describes SS220-CFast 2.0 signal segment, and Table 3-2, its power segment.
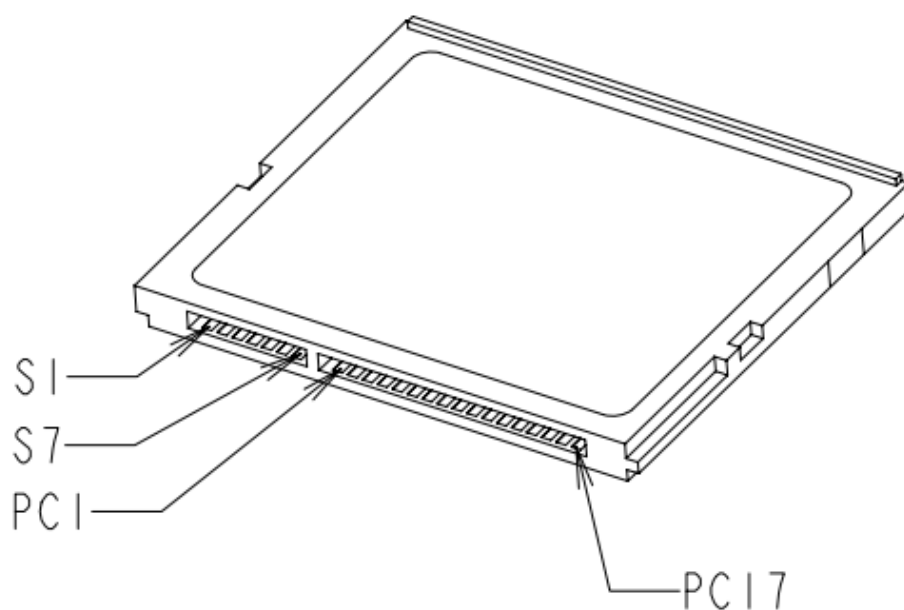
Figure 3-1 Pin Assignment

Table 3-1 Signal Segment

Pin	Definition	Description
S1	GND	Ground
S2	A+	SATA Differential Signal Pair A
S3	A-	
S4	GND	Ground
S5	B-	SATA Differential Signal Pair B
S6	B+	
S7	GND	Ground

Table 3-2 Power Segment

Pin	Definition	Type	Description
PC1	CDI	Input	Card Detect In
PC2	PGND	Device GND	Device GND
PC3	DEVSLP*	DEVSLP card input	DEVSLP enable
PC4			Reserved
PC5			Reserved
PC6			Reserved
PC7	PGND	Device GND	Device GND
PC8	LED1	LED Output	Power indicator
PC9	LED2	LED Output	Access indicator
PC10			Reserved
PC11			Write Protect**
PC12	IFDet	GND	Card output, connect to PGND on card
PC13	PWR	3.3V	Device power (3.3V)
PC14	PWR	3.3V	Device power (3.3V)
PC15	PGND	Device GND	Device GND
PC16	PGND	Device GND	Device GND
PC17	CDO	Output	Card Detect Out

*Optional
**Enabled by adjusting the pin "PC11" from high to low active
Notes about Write Protect:

Apacer implements the Virtual Write scheme that allows write commands to go through the flash controller and data is temporarily stored, but no data has been actually written into the flash. Once the host resets or restarts the system, all the temporarily stored data will disappear and nowhere to be found in the drive. Since the Virtual Write scheme runs at device level, it requires no software or driver installation and is independent from the host OS.
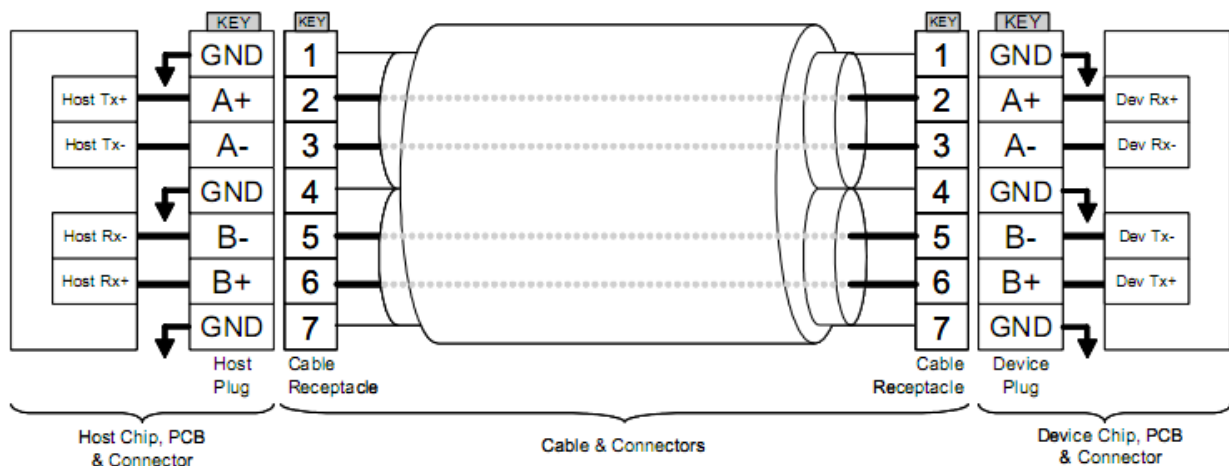

Figure 3-2 SATA Cable / Connector Connection Diagram

The connector on the left represents the Host with TX/RX differential pairs connected to a cable while the connector on the right shows the Device with TX/RX differential pairs also connected to the cable. Notice also the ground path connecting the shielding of the cable to the Cable Receptacle.

4. Product Specifications

4.1 Capacity

Capacity specifications of SS220-CFast 2.0 are available as shown in Table 4-1. It lists the specific capacity and the default numbers of heads, sectors and cylinders for each product line.

Table 4-1 Capacity Specifications

Capacity	Total bytes*	Cylinders	Heads	Sectors	Total LBA
4 GB	4,011,614,208	7,773	16	63	7,835,184
8 GB	8,012,390,400	15,525	16	63	15,649,200
16 GB	16,013,942,784	16,383	16	63	31,277,232
32 GB	32,017,047,552	16,383	16	63	62,533,296
64 GB	64,023,257,088	16,383	16	63	125,045,424

*Display of total bytes varies from file systems, which means not all of the bytes can be used for storage.
**Notes: 1 GB = 1,000,000,000 bytes; 1 sector = 512 bytes.
LBA count addressed in the table above indicates total user storage capacity and will remain the same throughout the lifespan of the device. However, the total usable capacity of the SSD is most likely to be less than the total physical capacity because a small portion of the capacity is reserved for device maintenance usages.

4.2 Performance

Performance of SS220-CFast 2.0 is listed below in Table 4-2.

Table 4-2 Performance Specifications

Performance / Capacity	4 GB	8 GB	16 GB	32 GB	64 GB
Sequential Read* (MB/s)	65	255	450	560	555
Sequential Write* (MB/s)	55	100	200	395	450
Random Read IOPS (4K)**	15,000	33,000	62,000	80,000	81,00
Random Write IOPS (4K)**	3,000	6,000	30,000	66,000	77,000

Note:
Results may differ from various flash configurations or host system setting.
*Sequential performance is based on CrystalDiskMark 5.2.1 with file size 1,000MB.
**Random performance measured using IOMeter with Queue Depth 32.

4.3 Environmental Specifications

Environmental specifications of SS220-CFast 2.0 product are shown in Table 4-3.

Table 4-3 Environmental Specifications

Item	Specifications
Operating temp.	0°C to 70°C (Standard); -40°C to 85°C (Wide)
Non-operating temp.	-40°C to 100°C
Operating vibration	7.69 GRMS, 20~2000 Hz/random (compliant with MIL-STD-810G)
Non-operating vibration	4.02 GRMS, 15~2000 Hz/random (compliant with MIL-STD-810G)
Operating shock	50G, 11ms
Non-operating shock	1500G, 0.5ms (compliant with MIL-STD-883K)

Note: This Environmental Specification table indicates the conditions for testing the device. Real world usages may affect the results.

4.4 Mean Time Between Failures (MTBF)

Mean Time Between Failures (MTBF) is predicted based on reliability data for the individual components in SS220-CFast 2.0. The prediction result for SS220-CFast 2.0 is more than 3,000,000 hours.

Note: The MTBF is predicated and calculated based on "Telcordia Technologies Special Report, SR-332, Issue 3" method.

4.5 Certification and Compliance

SS220-CFast 2.0 complies with the following standards:

- CE
- FCC
- RoHS
- MIL-STD-810G

4.6 Endurance

The endurance of a storage device is predicted by TeraBytes Written based on several factors related to usage, such as the amount of data written into the drive, block management conditions, and daily workload for the drive. Thus, key factors, such as Write Amplifications and the number of P/E cycles, can influence the lifespan of the drive.

Table 4-4 Endurance Specifications

Capacity	TeraBytes Written
4 GB	186
8 GB	267
16 GB	535
32 GB	1,329
64 GB	2,659

Note:
- The measurement assumes the data written to the SSD for test is under a typical and constant rate.
- The measurement follows the standard metric: 1 TB (Terabyte) = 1,024 GB.
- This estimation complies with JEDEC JESD-219, enterprise endurance workload of random data with payload size distribution.

5. Flash Management

5.1 Error Correction/Detection

SS220-CFast 2.0 implements a hardware ECC scheme, based on the BCH algorithm. It can detect and correct up to 72 bits error in 1K bytes.

5.2 Bad Block Management

Current production technology is unable to guarantee total reliability of NAND flash memory array. When a flash memory device leaves factory, it comes with a minimal number of initial bad blocks during production or out-of-factory as there is no currently known technology that produce flash chips free of bad blocks. In addition, bad blocks may develop during program/erase cycles. Since bad blocks are inevitable, the solution is to keep them in control. Apacer flash devices are programmed with ECC, page mapping technique and S.M.A.R.T to reduce invalidity or error. Once bad blocks are detected, data in those blocks will be transferred to free blocks and error will be corrected by designated algorithms.

5.3 Global Wear Leveling

Flash memory devices differ from Hard Disk Drives (HDDs) in terms of how blocks are utilized. For HDDs, when a change is made to stored data, like erase or update, the controller mechanism on HDDs will perform overwrites on blocks. Unlike HDDs, flash blocks cannot be overwritten and each P/E cycle wears down the lifespan of blocks gradually. Repeatedly program/erase cycles performed on the same memory cells will eventually cause some blocks to age faster than others. This would bring flash storages to their end of service term sooner. Global wear leveling is an important mechanism that levels out the wearing of all blocks so that the wearing-down of all blocks can be almost evenly distributed. This will increase the lifespan of SSDs.

5.4 Flash Translation Layer – Page Mapping

Page mapping is an advanced flash management technology whose essence lies in the ability to gather data, distribute the data into flash pages automatically, and then schedule the data to be evenly written. Page-level mapping uses one page as the unit of mapping. The most important characteristic is that each logical page can be mapped to any physical page on the flash memory device. This mapping algorithm allows different sizes of data to be written to a block as if the data is written to a data pool and it does not need to take extra operations to process a write command. Thus, page mapping is adopted to increase random access speed and improve SSD lifespan, reduce block erase frequency, and achieve optimized performance and lifespan.

5.5 ATA Secure Erase

ATA Secure Erase is an ATA disk purging command currently embedded in most of the storage drives. Defined in ATA specifications, (ATA) Secure Erase is part of Security Feature Set that allows storage drives to erase all user data areas. The erase process usually runs on the firmware level as most of the ATA-based storage media currently in the market are built-in with this command. ATA Secure Erase can securely wipe out the user data in the drive and protects it from malicious attack.

5.6 Power Failure Management

Power Failure Management plays a crucial role when power supply becomes unstable. Power disruption may occur when users are storing data into the SSD, leading to instability in the drive. However, with Power Failure Management, a firmware protection mechanism will be activated to scan pages and blocks once power is resumed. Valid data will be transferred to new blocks for merging and the mapping table will be rebuilt. Therefore, data reliability can be reinforced, preventing damage to data stored in the NAND Flash.

5.7 TRIM

TRIM is a SATA command that helps improve the read/write performance and efficiency of solid-state drives (SSD). The command enables the host operating system to inform SSD controller which blocks contain invalid data, mostly because of the erase commands from host. The invalid will be discarded permanently and the SSD will retain more space for itself.

5.8 Device Sleep (DevSleep or DEVSLP) Mode (optional)

Device Sleep is a feature that allows SATA devices to enter a low power mode by designating a particular pin as DEVSLP signal with an aim to reducing power consumption.
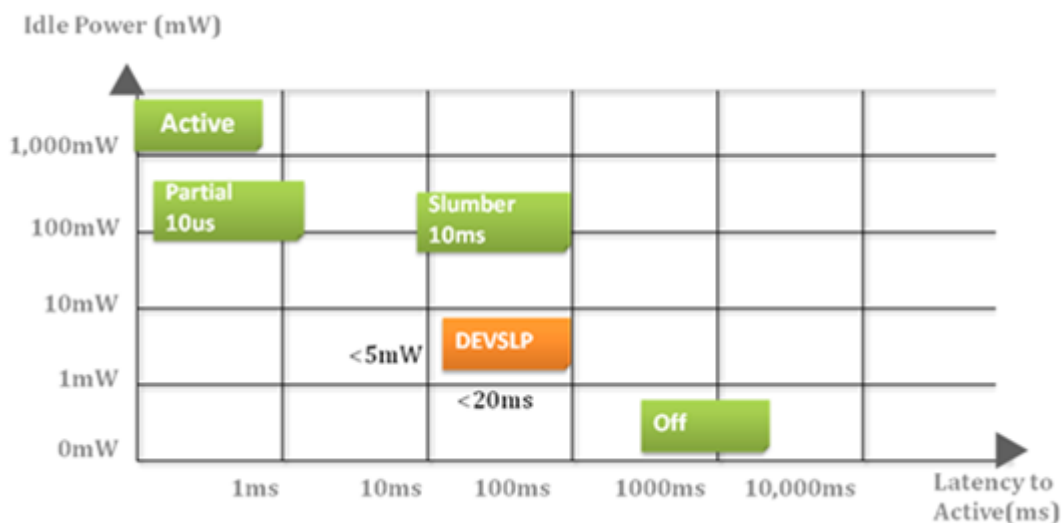
5.9 SATA Power Management

By complying with SATA 6 Gb/s specifications, the SSD supports the following SATA power saving modes:

- ACTIVE: PHY ready, full power, Tx & Rx operational

- PARTIAL: Reduces power, resumes in under 10 μs (microseconds)

- SLUMBER: Reduces power, resumes in under 10 ms (milliseconds)

- HIPM: Host-Initiated Power Management

- DIPM: Device-Initiated Power Management

- AUTO-SLUMBER: Automatic transition from partial to slumber.

- Device Sleep (DevSleep or DEVSLP): PHY powered down; power consumption $\leqq$ 5 mW; host assertion time $\leqq$ 10 ms; exit timeout from this state $\leqq$ 20 ms (unless specified otherwise in SATA Identify Device Log).

Note:
1. The behaviors of power management features would depend on host/device settings.
2. Device Sleep mode is optional depending on product ordering selections.

6. Software Interface

6.1 Command Set

Table 6-1 Command Set

Code	Command	Code	Command
E5h	CHECK POWER MODE	F6h	SECURITY DISABLE PASSWORD
90h	EXECUTE DIAGNOSTICS	F3h	SECURITY ERASE PREPARE
E7h	FLUSH CACHE	F4h	SECURITY ERASE UNIT
ECh	IDENTIFY DEVICE	F5h	SECURITY FREEZE LOCK
E3h	IDLE	F1h	SECURITY SET PASSWORD
E1h	IDLE IMMEDIATE	F2h	SECURITY UNLOCK
91h	INITIALIZE DEVICE PARAMETERS	7Xh	SEEK
C8h	READ DMA	EFh	SET FEATURES
25h	READ DMA EXT	C6h	SET MULTIPLE MODE
60h	READ FPDMA QUEUED	E6h	SLEEP
47h	READ LOG DMA EXT	B0h	S.M.A.R.T.
2Fh	READ LOG EXT	E2h	STANDBY
C4h	READ MULTIPLE	E0h	STANDBY IMMEDIATE
20 or 21h	READ SECTOR(S)	CAh	WRITE DMA
40 or 41h	READ VERIFY SECTOR(S)	35h	WRITE DMA EXT
10h	RECALIBRATE	61h	WRITE FPDMA QUEUED
57h	WRITE LOG DMA EXT	3Fh	WRITE LOG EXT
C5h	WRITE MULTIPLE	30h or 31h	WRITE SECTOR(S)

6.2 S.M.A.R.T.

S.M.A.R.T. is an abbreviation for Self-Monitoring, Analysis and Reporting Technology, a self-monitoring system that provides indicators of drive health as well as potential disk problems. It serves as a warning for users from unscheduled downtime by monitoring and displaying critical drive information. Ideally, this should allow taking proactive actions to prevent drive failure and make use of S.M.A.R.T. information for future product development reference.

Apacer devices use the standard SMART command B0h to read data out from the drive to activate our S.M.A.R.T. feature that complies with the ATA/ATAPI specifications. S.M.A.R.T. Attribute IDs shall include initial bad block count, total later bad block count, maximum erase count, average erase count, power on hours and power cycle. When the S.M.A.R.T. Utility running on the host, it analyzes and reports the disk status to the host before the device reaches in critical condition.

Note: Attribute IDs may vary from product models due to various solution design and supporting capabilities.

Apacer memory products come with S.M.A.R.T. commands and subcommands for users to obtain information of drive status and to predict potential drive failures. Users can take advantage of the following commands/subcommands to monitor the health of the drive.

Code	SMART Subcommand
D0h	READ DATA
D1h	READ ATTRIBUTE THRESHOLDS
D2h	ENABLE/DISABLE ATTRIBUTE AUTOSAVE
D4h	EXECUTE OFF-LINE IMMEDIATE
D5h	SMART READ LOG
D6h	SMART WRITE LOG
D8h	ENABLE OPERATIONS
D9h	DISABLE OPERATIONS
DAh	RETURN STATUS

General SMART attribute structure

Byte	Description
0	ID (Hex)
1 – 2	Status Flag
3	Value
4	Worst
5*-11	Raw Data

*Byte 5: LSB

SMART attribute ID list

ID (Hex)	Attribute Name
9 (0x09)	Power-on Hours
12 (0x0C)	Power Cycle Count
163 (0xA3)	Max. Erase Count
164 (0xA4)	Avg. Erase Count
166 (0xA6)	Total Later Bad Block Count
167 (0xA7)	SSD Protect Mode (Vendor Specific)
168 (0xA8)	SATA PHY Error Count
171 (0xAB)	Program Fail Count
172 (0xAC)	Erase Fail Count
175 (0xAF)	Bad Cluster Table Count
192 (0xC0)	Unexpected Power Loss Count
194 (0xC2)	Temperature
231 (0xE7)	Lifetime Left
241 (0xF1)	Total Sectors of Write

7. Electrical Specifications

7.1 Operating Voltage

Table 7-1 lists the supply voltage for SS220-CFast 2.0.

Table 7-1 Operating Range

Parameter	Symbol	Min	Type	Max	Units
Power Supply	Vcc	3.135	3.3	3.465	V

7.2 Power Consumption

Table 7-2 lists the power consumption for SS220-CFast 2.0.

Table 7-2 Power Consumption

Capacity / Mode	4 GB	8 GB	16 GB	32 GB	64 GB
Active (mA)	265	260	345	460	510
Idle (mA)	90	80	85	85	80

Note:
*All values are typical and may vary depending on flash configurations or host system settings.
**Active power is an average power measurement performed using CrystalDiskMark with 128KB sequential read/write transfers.

8. Physical Characteristics
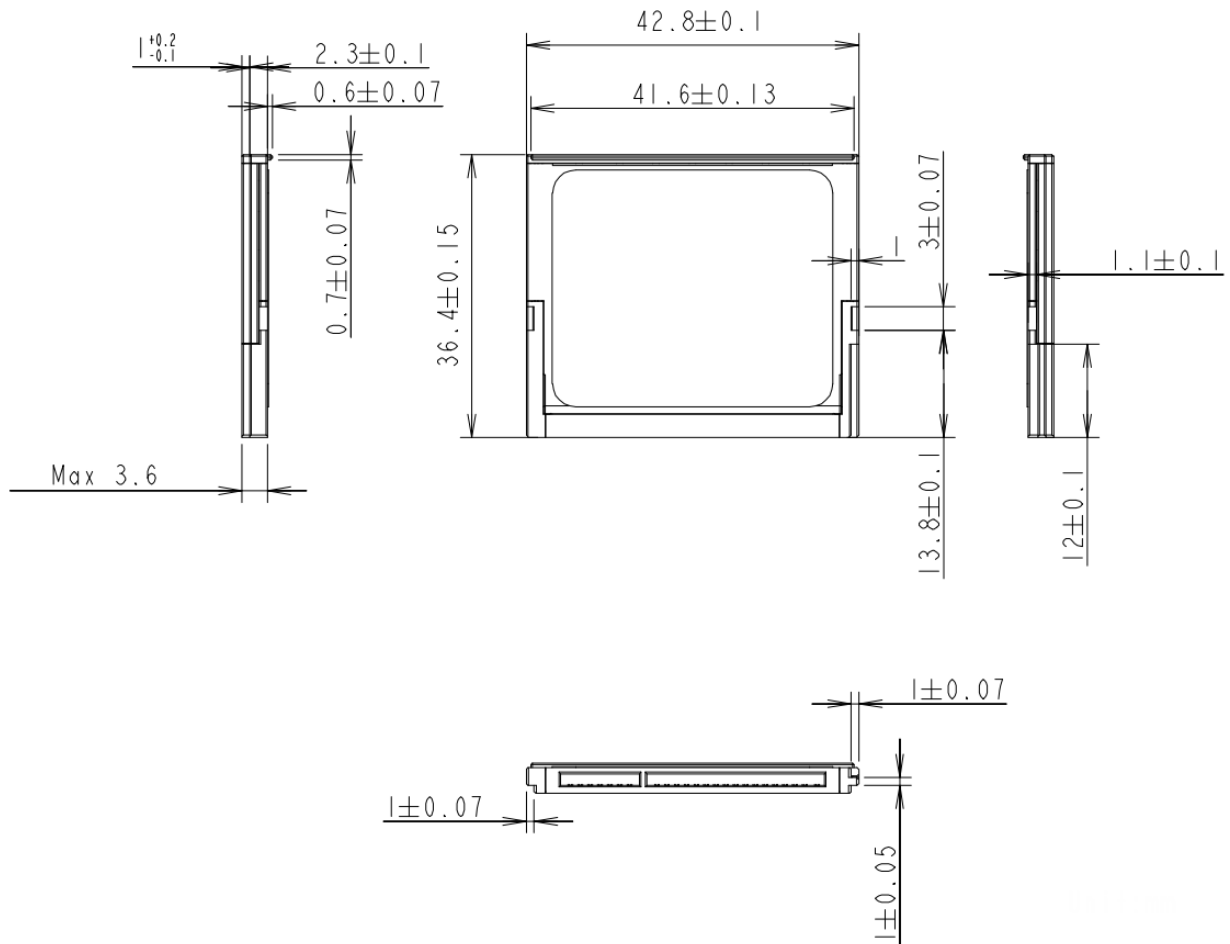
Unit: ㎜

Figure 8-1 Physical Dimensions

9. Product Ordering Information

9.1 Product Code Designations

AP CFA xxxG GDX X – X 6X T

Flash Type

FW Version
6E: Without DEVSLP
6F: With DEVSLP

Operating Temperature Range
Blank: Standard Temperature
W: Wide Temperature

N: Standard
D: Hi-Speed

Solution Version
A: Standard:
W: Write Protect

Capacity
004G = 4GB
008G = 8GB
016G = 16GB
032G = 32GB
064G = 64GB

Model Name

Apacer Product Code
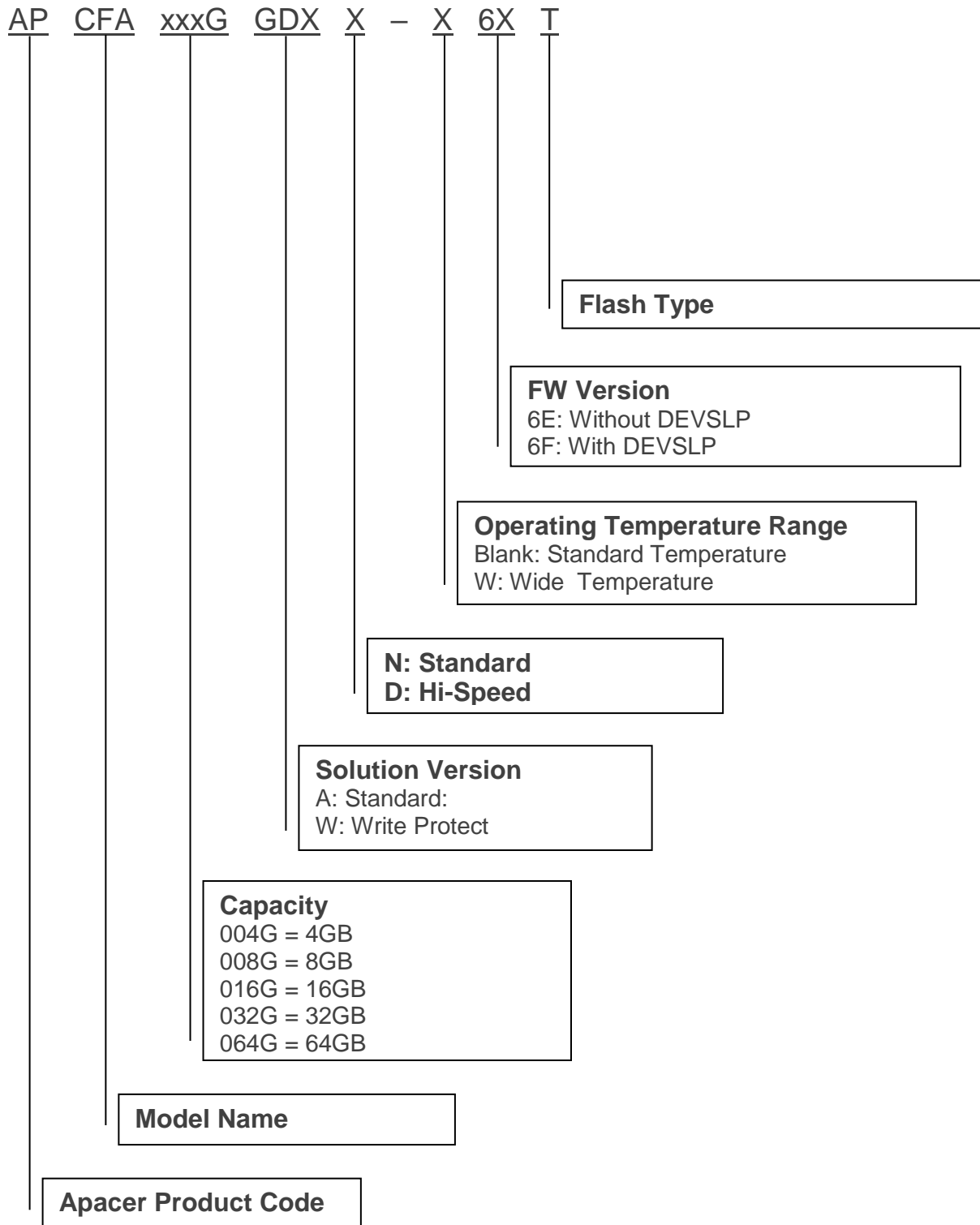
9.2 Valid Combinations

9.2.1 Without DEVSLP

Capacity	Standard Temperature	Wide Temperature
4GB	APCFA004GGDAN-6ET	APCFA004GGDAN-W6ET
8GB	APCFA008GGDAD-6ET	APCFA008GGDAD-W6ET
16GB	APCFA016GGDAD-6ET	APCFA016GGDAD-W6ET
32GB	APCFA032GGDAD-6ET	APCFA032GGDAD-W6ET
64GB	APCFA064GGDAD-6ET	APCFA064GGDAD-W6ET

9.2.2 With DEVSLP

Capacity	Standard Temperature	Wide Temperature
4GB	APCFA004GGDAN-6FT	APCFA004GGDAN-W6FT
8GB	APCFA008GGDAD-6FT	APCFA008GGDAD-W6FT
16GB	APCFA016GGDAD-6FT	APCFA016GGDAD-W6FT
32GB	APCFA032GGDAD-6FT	APCFA032GGDAD-W6FT
64GB	APCFA064GGDAD-6FT	APCFA064GGDAD-W6FT

9.2.3 Without DEVSLP + Write Protect

Capacity	Standard Temperature	Wide Temperature
4GB	APCFA004GGDWN-6ET	APCFA004GGDWN-W6ET
8GB	APCFA008GGDWD-6ET	APCFA008GGDWD-W6ET
16GB	APCFA016GGDWD-6ET	APCFA016GGDWD-W6ET
32GB	APCFA032GGDWD-6ET	APCFA032GGDWD-W6ET
64GB	APCFA064GGDWD-6ET	APCFA064GGDWD-W6ET

9.2.4 With DEVSLP + Write Protect

Capacity	Standard Temperature	Wide Temperature
4GB	APCFA004GGDWN-6FT	APCFA004GGDWN-W6FT
8GB	APCFA008GGDWD-6FT	APCFA008GGDWD-W6FT
16GB	APCFA016GGDWD-6FT	APCFA016GGDWD-W6FT
32GB	APCFA032GGDWD-6FT	APCFA032GGDWD-W6FT
64GB	APCFA064GGDWD-6FT	APCFA064GGDWD-W6FT

Note: Valid combinations are those products in mass production or will be in mass production. Consult your Apacer sales representative to confirm availability of valid combinations and to determine availability of new combinations.

Revision History

Revision	Description	Date
1.0	Official release	7/17/2018
1.1	Added 4GB support	8/9/2018
1.2	- Added Endurance to Specifications Overview - Added 4.6 Endurance	9/6/2018
1.3	Updated 4GB valid combinations at 9. Product Ordering Information	10/4/2018
1.4	- Renamed extended temperature to wide temperature - Updated Performance and Power Consumption on Specifications Overview page - Updated 4.2 Performance and 7.2 Power Consumption - Updated technology description for 5.6 Power Failure Management - Updated 9. Product Ordering Information due to FW change	12/12/2019
1.5	- Changed SATA 6.0 Gbps to SATA 6 Gb/s in accordance with SATA naming guidelines - Updated operating/non-operating vibration spec at Table 4-3 Environmental Specifications - Updated MIL compliance from MIL-STD-810F to MIL-STD-810G at 4.5 Certification and Compliance - Capitalized every letter for commands at 6.1 Command Set and SMART subcommand at 6.2 S.M.A.R.T.	3/19/2020
1.6	- Added Write Protect support - Update MTBF to >3,000,000 hours - Updated 4.4 Mean Time Between Failures (MTBF) - Updated 9. Product Ordering Information by adding 9.2.3 and 9.2.4 valid combinations	3/17/2021

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